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View Online at https://aerobasegroup.com/nsn/5962-01-372-6629

Body Length:

Between 1.260 inches and 1.280 inches

Body Width:

Between 0.180 inches and 0.200 inches

Body Height:

Between 0.290 inches and 0.310 inches

Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

End Application:

Eolorops

Features Provided:

Electrostatic sensitive and burn in, mil-std-883, class b and monolithic and ultraviolet erasable and tested to mil-std-883 and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-9 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

0.5 volts total supply and 7.0 volts total supply

Time Rating Per Chacteristic:

25.00 nanoseconds af output megawatts

Memory Device Type:

Pal

Special Features:

Esd; checksum d0ee; filename; 1062u15.Jed; altered item using 67268, 59628753901lx

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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67268-5962-87539 government standard

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

